

High-throughput identification of defects in SiC

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Quantum Application

First generation:

- LED
- Laser
- Sensors

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Quantum Application

Second generation:

- Simulation
- Cryptography
- Computing

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Specific Applications

Point defect applications:

- Nano thermometers in cells

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Kucsko, Georg, et al. Nature 500.7460 (2013)

Specific Applications

Point defect applications:

- Nano thermometers in cells
- Chemical sensors, detect 1 part per million

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Aslam, Nabeel, et al. Science 357.6346 (2017)

Specific Applications

Point defect applications:

- Nano thermometers in cells
- Chemical sensors, detect 1 part per million
- Photonics, long range entanglement

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Hensen, Bas, et al. Nature 526.7575 (2015)

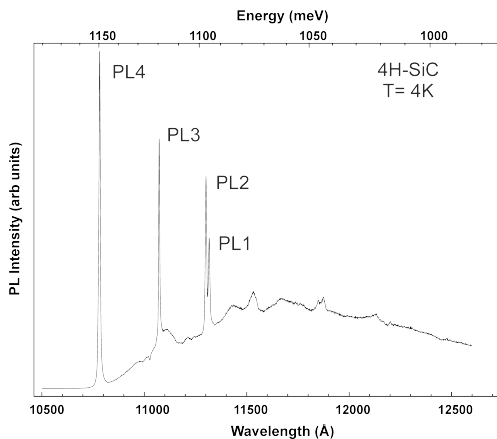
Specific Applications

Point defect applications:

- Nano thermometers in cells
- Chemical sensors, detect 1 part per million
- Photonics, long range entanglement
- and many more...

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Photoluminescence to Detect Point Defects

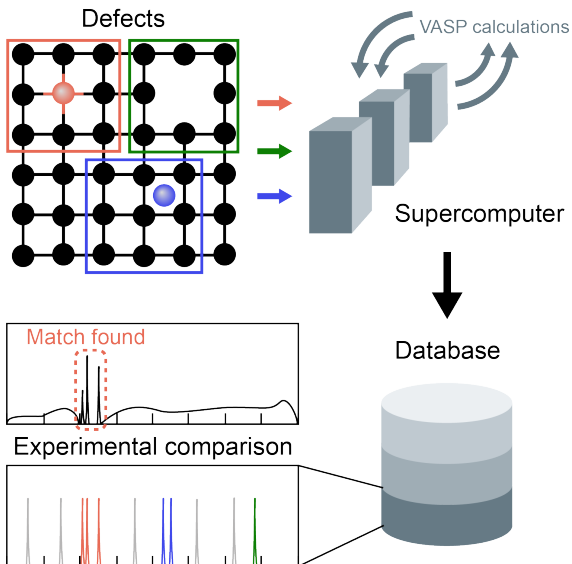


Courtesy of Dr. Ivan Ivanov, LiU

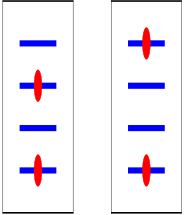
Movie

The video is available here: <https://d.pr/GKmKFW>

High-Throughput Search



Automatic Workflow

Step	Example	Number of calculations
Host	SiC	1
Defect	Divacancy	1
Configurations	hh,hk,kh,kk	$\approx 1 - 10 - ?$
Charge state	--,-,0,+,++	5
Spin of defect	0,1,1/2	≈ 3
Excitations		≈ 10

Automatic Workflow

To fully characterize one defect in one host material would take about 500 calculations.

With PBE each run would take approximately 800 core-hours.

Total of 400 000 core-hours per defect.

Results

Stored in database.

Demonstration of prototype web interface.

Conclusion

- Point defects are useful in a wide range of applications.
- A huge task to find new and interesting point defects.
- Big challenge to match the experimental results with the calculated data in the database.

Thanks to Viktor Ivády, Rickard Armiento, and Igor Abrikosov.

